



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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CPH6635

Power MOSFET

30V, 0.4A, 3.7Ω, -20V, -1.5A, 280mΩ, Complementary Dual CPH6

ON Semiconductor®

<http://onsemi.com>

Features

- Excellent ON-resistance characteristic (P-Channel : $R_{DS(on)1}=215m\Omega$ (typ.))
- Optimal for load switch use (N-Channel for drive is embedded)
- N-Channel : 1.5V drive, P-Channel : 1.8V drive
- Halogen Free compliance

Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	N-channel	P-channel	Unit
Drain to Source Voltage	V_{DSS}		30	-20	V
Gate to Source Voltage	V_{GSS}		± 10	± 10	V
Drain Current (DC)	I_D		0.4	-1.5	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	1.6	-6.0	A
Allowable Power Dissipation	P_D	When mounted on ceramic substrate (900mm ² x 0.8mm) 1unit	0.8		W
Channel Temperature	T_{ch}		150		°C
Storage Temperature	T_{stg}		-55 to +150		°C

This product is designed to "ESD immunity < 200V**", so please take care when handling.

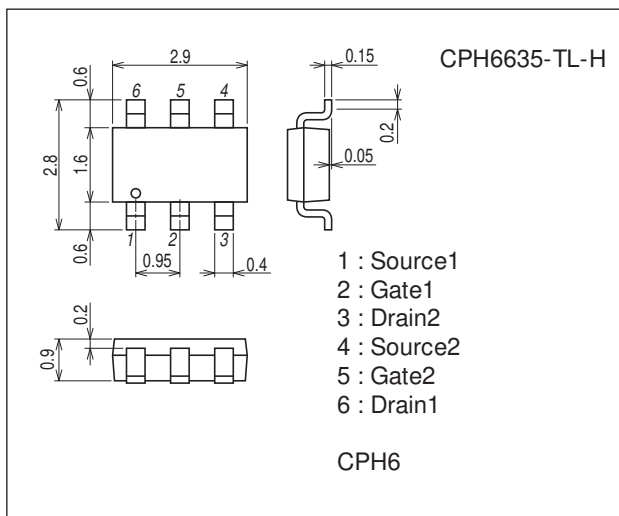
* Machine Model

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

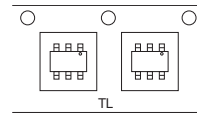
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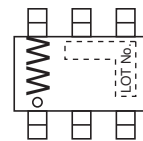
Ordering & Package Information

Device	Package	Shipping	memo
CPH6635-TL-H	CPH6 SC-74, SOT-26, SOT-45	3,000 pcs./reel	Pb Free and Halogen Free

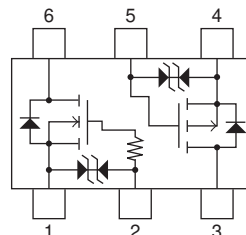
Packing Type: TL



Marking



Electrical Connection



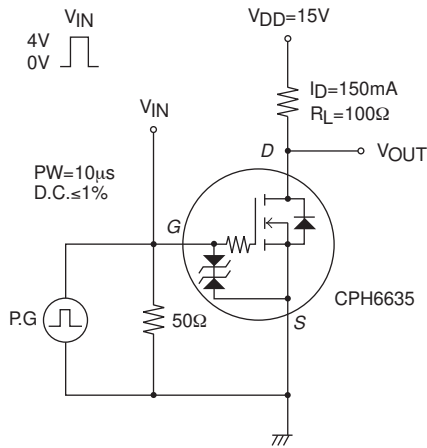
CPH6635

Electrical Characteristics at Ta=25°C

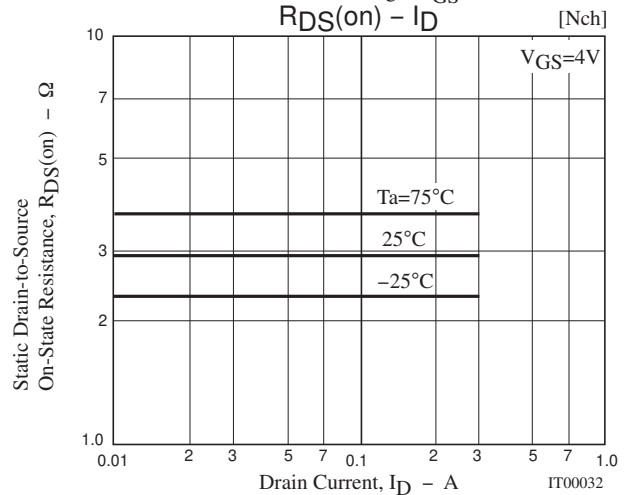
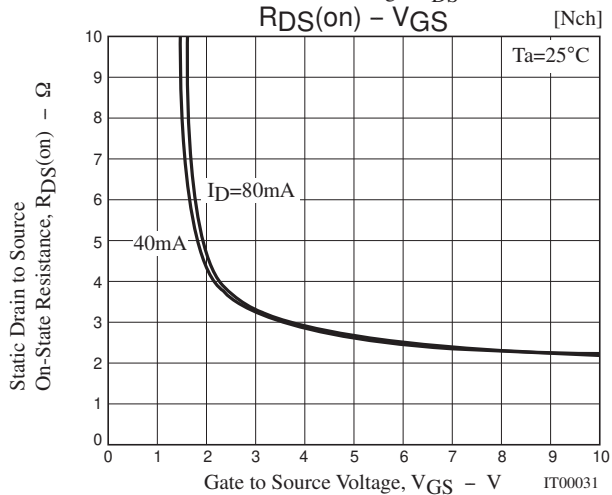
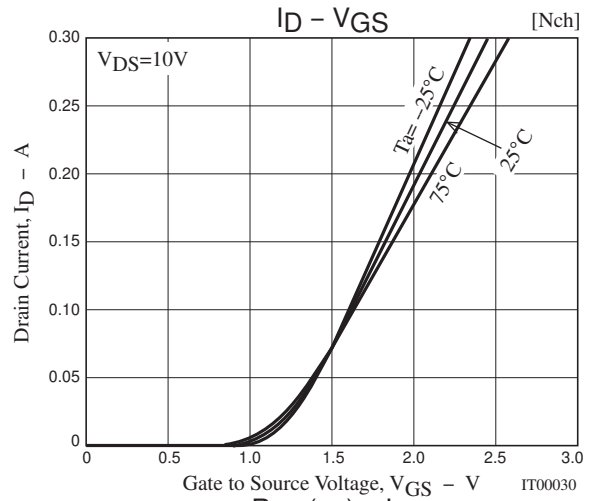
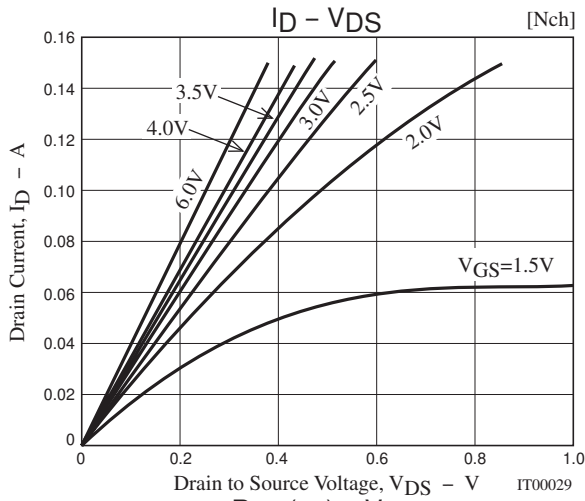
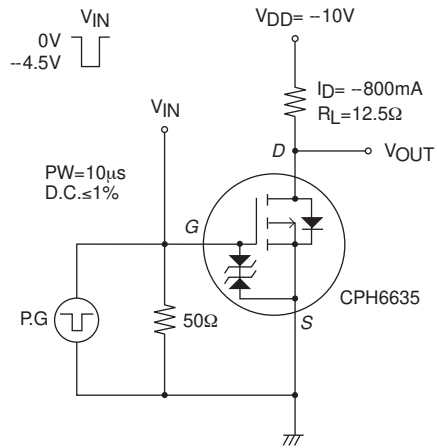
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[N-channel]						
Drain to Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0V			1	μA
Gate to Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=10V, ID=100μA	0.4		1.3	V
Forward Transfer Admittance	yfs	VDS=10V, ID=80mA		0.22		S
Static Drain to Source On-State Resistance	RDS(on)1	ID=80mA, VGS=4V		2.9	3.7	Ω
	RDS(on)2	ID=40mA, VGS=2.5V		3.7	5.2	Ω
	RDS(on)3	ID=10mA, VGS=1.5V		6.4	12.8	Ω
Input Capacitance	Ciss	VDS=10V, f=1MHz		7		pF
Output Capacitance	Coss			5.9		pF
Reverse Transfer Capacitance	Crss			2.3		pF
Turn-ON Delay Time	td(on)		See specified Test Circuit.		19	
Rise Time	tr			65		ns
Turn-OFF Delay Time	td(off)			155		ns
Fall Time	tf			120		ns
Total Gate Charge	Qg	VDS=10V, VGS=10V, ID=150mA			1.58	
Gate to Source Charge	Qgs			0.26		nC
Gate to Drain "Miller" Charge	Qgd			0.31		nC
Diode Forward Voltage	VSD	IS=150mA, VGS=0V		0.87	1.2	V
[P-channel]						
Drain to Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-20			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-20V, VGS=0V			-1	μA
Gate to Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=-10V, ID=-1mA	-0.4		-1.4	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-800mA		1.9		S
Static Drain to Source On-State Resistance	RDS(on)1	ID=-800mA, VGS=-4.5V		215	280	mΩ
	RDS(on)2	ID=-400mA, VGS=-2.5V		310	434	mΩ
	RDS(on)3	ID=-200mA, VGS=-1.8V		450	675	mΩ
Input Capacitance	Ciss	VDS=-10V, f=1MHz		120		pF
Output Capacitance	Coss			26		pF
Reverse Transfer Capacitance	Crss			20		pF
Turn-ON Delay Time	td(on)		See specified Test Circuit.		5.3	
Rise Time	tr			9.7		ns
Turn-OFF Delay Time	td(off)			16		ns
Fall Time	tf			14		ns
Total Gate Charge	Qg	VDS=-10V, VGS=-4V, ID=-1.5A			1.7	
Gate to Source Charge	Qgs			0.28		nC
Gate to Drain "Miller" Charge	Qgd			0.47		nC
Diode Forward Voltage	VSD	IS=-1.5A, VGS=0V		-0.9	-1.5	V

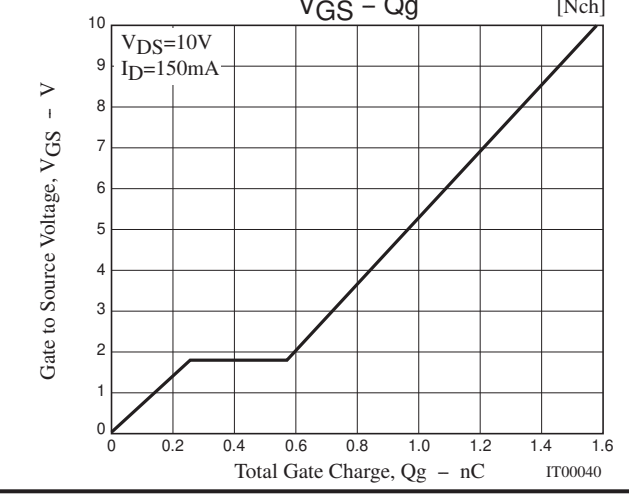
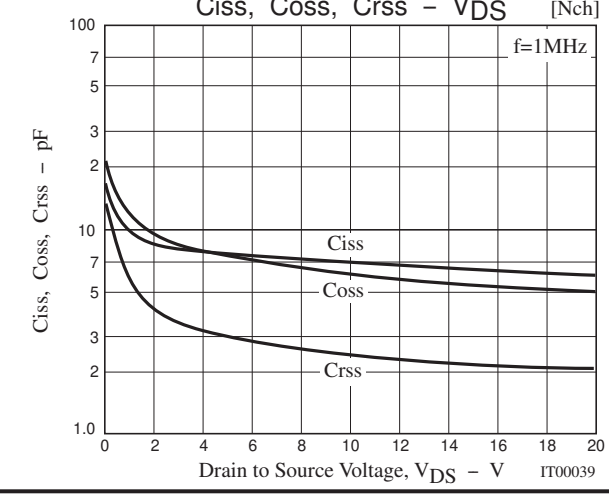
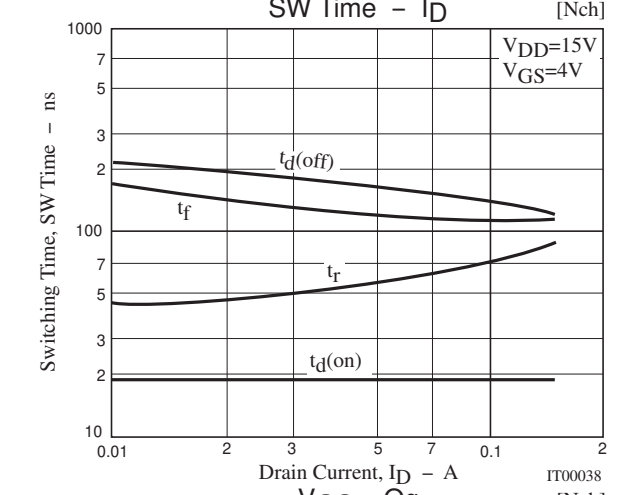
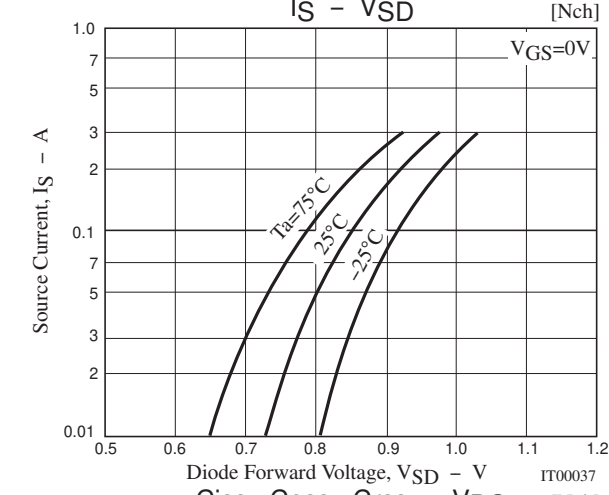
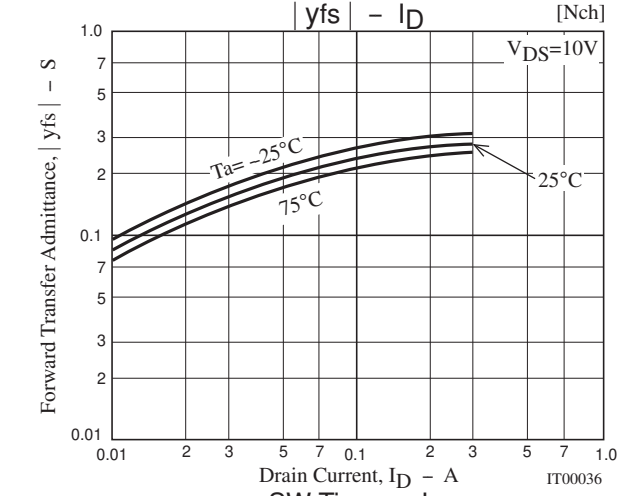
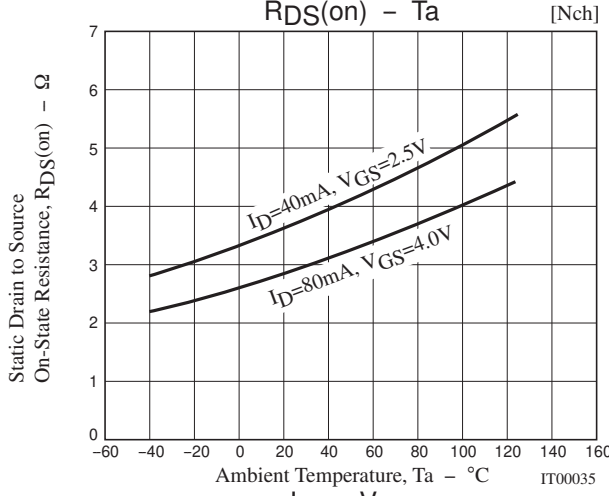
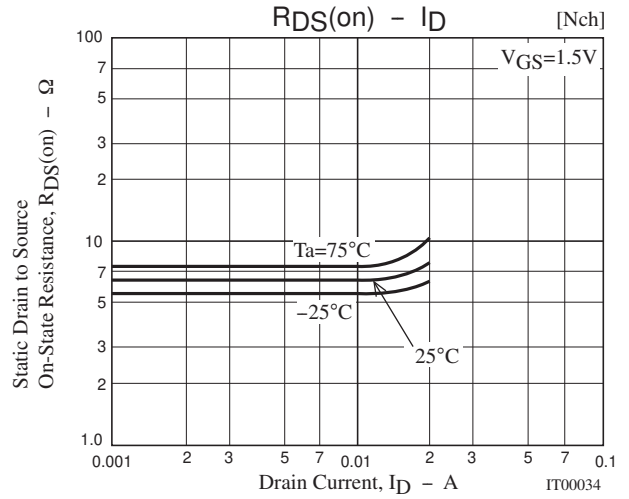
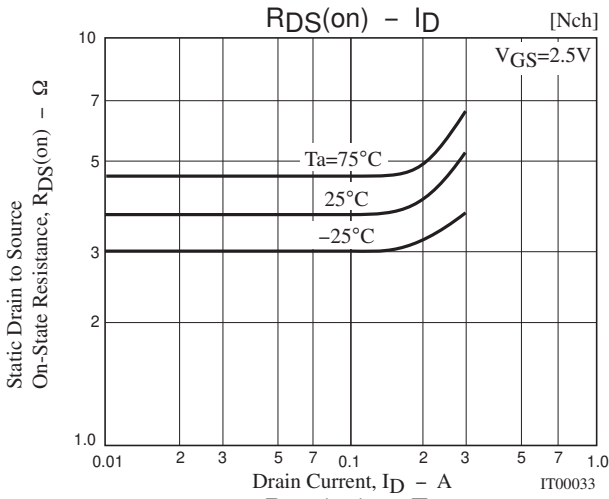
Switching Time Test Circuit

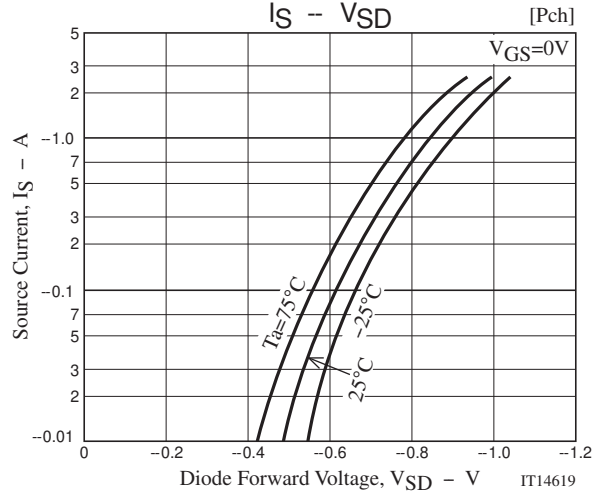
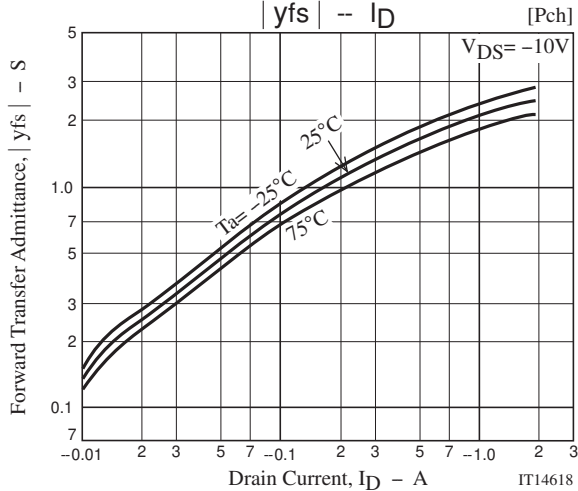
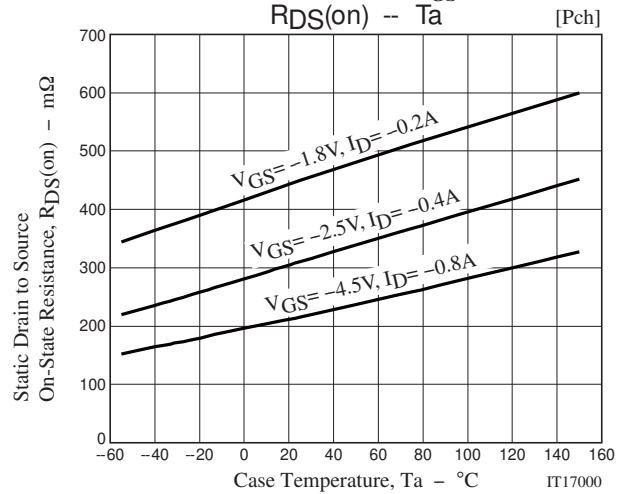
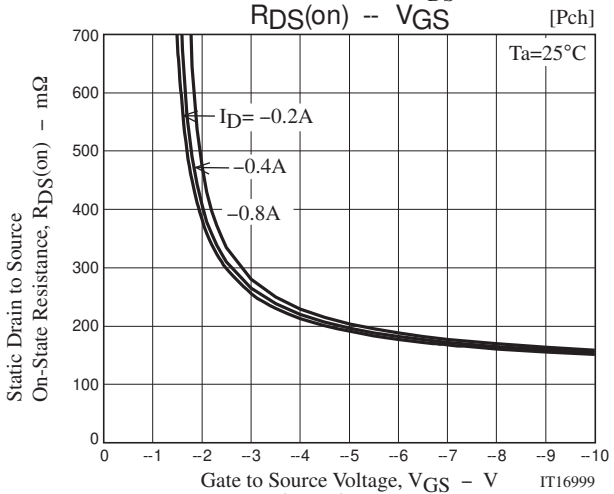
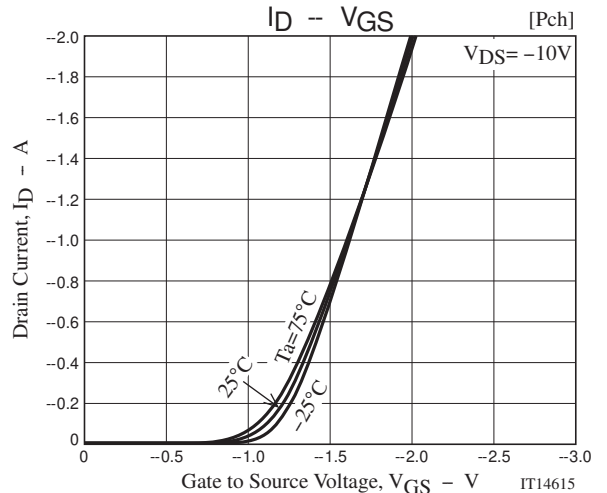
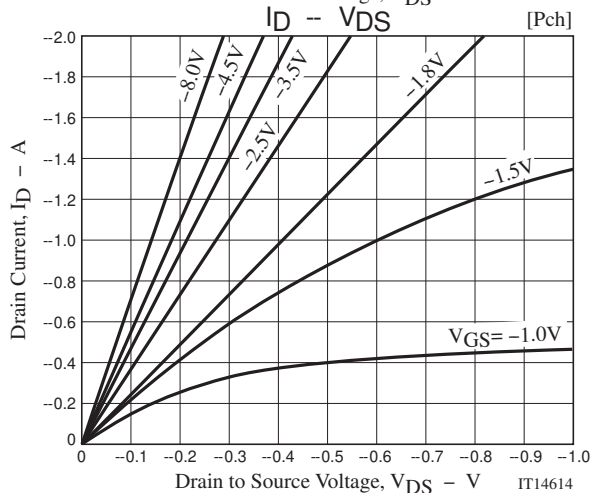
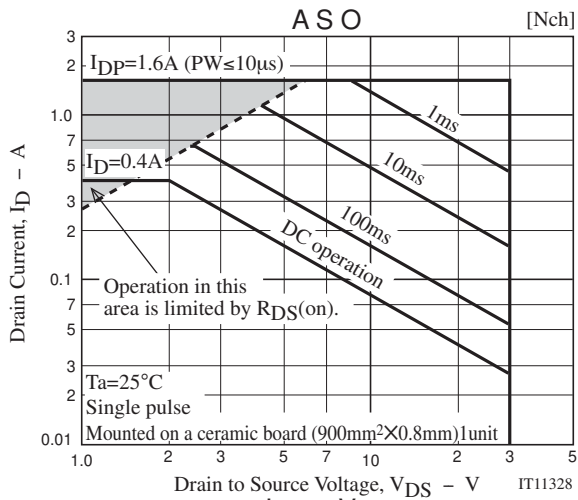
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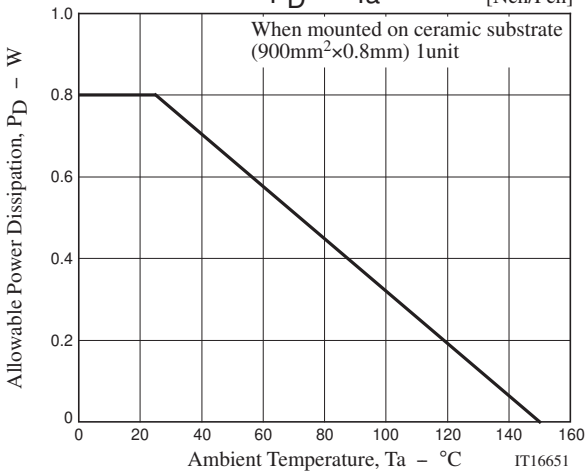
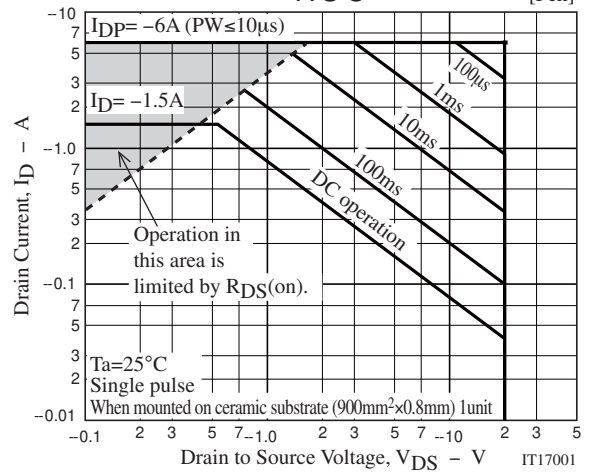
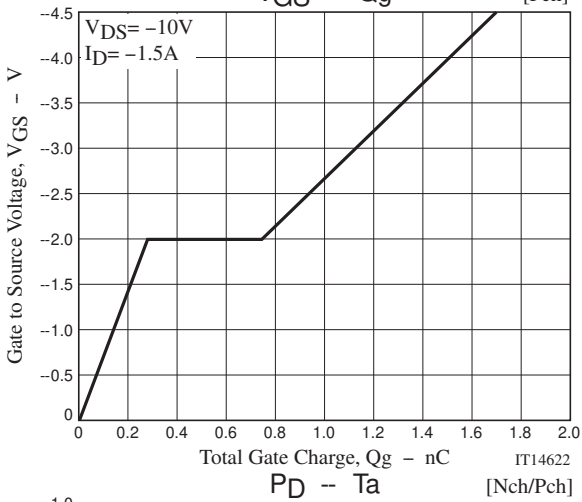
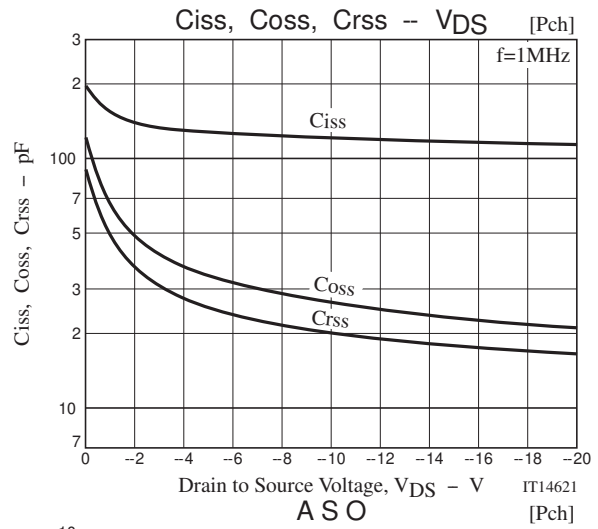
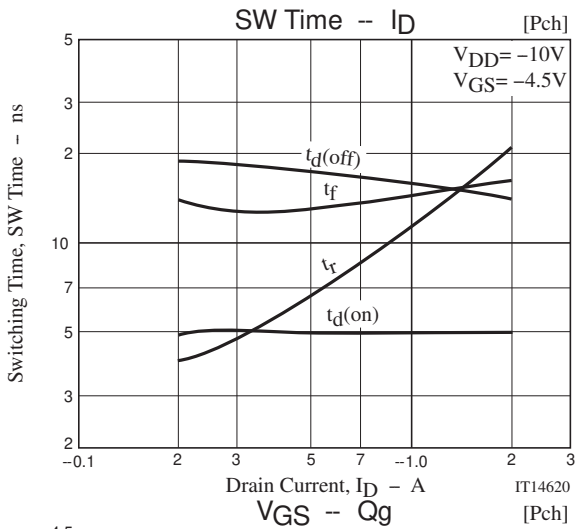


[P-channel]









Note on usage : Since the CPH6635 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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